TPS737xx 1-A Low-Dropout Regulator with Reverse Current Protection

1 Features
• Qualified for automotive applications
• AEC-Q100 qualified with the following results:
  – Device temperature grade 1: −40°C to 125°C ambient operating temperature range
  – Device HBM ESD classification level 2
  – Device CDM ESD classification level C4A
• Stable with 1-µF or larger ceramic output capacitor
• Input voltage range: 2.2 V to 5.5 V
• Ultra-low dropout voltage: 130 mV (typical) at 1 A
• Excellent load transient response, even with only 1-µF output capacitor
• NMOS topology delivers low reverse leakage current
• 1% initial accuracy
• 3% overall accuracy over line, load, and temperature
• Less than 20-nA (typical) quiescent current in shutdown mode
• Thermal shutdown and current limit for fault protection
• Available in multiple output voltage versions

2 Applications
• Point of load regulation for DSPs, FPGAs, ASICs, and microprocessors
• Post-regulation for switching supplies
• Portable and battery-powered equipment

3 Description
The TPS737xx-Q1 family of linear low-dropout (LDO) voltage regulators uses an NMOS pass element in a voltage-follower configuration. This topology is relatively insensitive to output capacitor value and ESR, allowing a wide variety of load configurations. Load transient response is excellent, even with a small 1-µF ceramic output capacitor. The NMOS topology also allows very low dropout.

The TPS737xx-Q1 family uses an advanced BiCMOS process to yield high precision while delivering very low dropout voltages and low ground pin current. Current consumption, when not enabled, is under 20 nA and ideal for portable applications. These devices are protected by thermal shutdown and foldback current limit.

Device Information

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>PACKAGE</th>
<th>BODY SIZE (NOM)</th>
</tr>
</thead>
<tbody>
<tr>
<td>TPS737-Q1</td>
<td>VSON (8)</td>
<td>3.00 mm × 3.00 mm</td>
</tr>
</tbody>
</table>

(1) For all available packages, see the orderable addendum at the end of the data sheet.

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.
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# 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (July 2016) to Revision B Page

- Changed device temperature grade AEC-Q100 Features bullet ........................................ 1
- Deleted sub-bullets from Features output voltage version bullet ....................................... 1

Changes from Original (December 2008) to Revision A Page

- Added Device Information table, Pin Configuration and Functions section, Specifications section, ESD Ratings table, Recommended Operating Conditions table, Thermal Information table, Detailed Description section, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section ........................................ 1
- Deleted Ordering Information Table; see POA at the end of the datasheet ............................ 1
## 5 Pin Configuration and Functions

### DRB Package
8-Pin VSON
Top View

<table>
<thead>
<tr>
<th>PIN</th>
<th>I/O</th>
<th>DESCRIPTION</th>
</tr>
</thead>
</table>
| EN  | 5   | I \( \text{Driving the enable pin (EN) high turns on the regulator. Driving this pin low puts the}
|     |     |             | \( \text{regulator into shutdown mode. See Enable Pin and Shutdown for more details. EN must not be left}
|     |     |             | \( \text{floating and can be connected to IN if not used.}\) |
| FB  | 3   | I \( \text{Adjustable voltage version only. This is the input to the control loop error amplifier,}
|     |     |             | \( \text{and it is used to set the output voltage of the device.}\) |
| GND | 4,Pad | G \( \text{Ground}\) |
| IN  | 8   | I \( \text{Unregulated input supply}\) |
| NR  | 3   | — \( \text{Fixed voltage versions only. Connecting an external capacitor to this pin bypasses noise}
|     |     |             | \( \text{generated by the internal bandgap, reducing output noise to very low levels.}\) |
| OUT | 1   | O \( \text{Regulator output. A 1-µF or larger capacitor of any type is required for stability.}\) |
| NC  | 2, 6, 7 | — \( \text{No internal connection}\) |
6 Specifications

6.1 Absolute Maximum Ratings
over operating free-air temperature range (unless otherwise noted)(1)

<table>
<thead>
<tr>
<th></th>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input supply voltage</td>
<td>–0.3</td>
<td>6</td>
<td>V</td>
</tr>
<tr>
<td>Enable voltage</td>
<td>–0.3</td>
<td>6</td>
<td>V</td>
</tr>
<tr>
<td>Output voltage</td>
<td>–0.3</td>
<td>5.5</td>
<td>V</td>
</tr>
<tr>
<td>Input voltage</td>
<td>–0.3</td>
<td>6</td>
<td>V</td>
</tr>
<tr>
<td>Peak output current</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Output short-circuit duration</td>
<td>Indefinite</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Junction temperature range, $T_J$</td>
<td>–55</td>
<td>150</td>
<td>°C</td>
</tr>
<tr>
<td>Storage temperature, $T_{stg}$</td>
<td>–65</td>
<td>150</td>
<td>°C</td>
</tr>
</tbody>
</table>

(1) Stresses beyond those listed under **Absolute Maximum Ratings** may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under **Recommended Operating Conditions**. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

<table>
<thead>
<tr>
<th>ESD Model</th>
<th>VALUE</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Electrostatic discharge</td>
<td>±2000</td>
<td>V</td>
</tr>
<tr>
<td>Human-body model (HBM), per AEC Q100-002(1)</td>
<td>±2000</td>
<td>V</td>
</tr>
<tr>
<td>Charged-device model (CDM), per AEC Q100-011</td>
<td>±500</td>
<td>V</td>
</tr>
</tbody>
</table>

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions
over operating free-air temperature range (unless otherwise noted)

<table>
<thead>
<tr>
<th></th>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{IN}$ Input supply voltage</td>
<td>2.2</td>
<td>5.5</td>
<td>V</td>
</tr>
<tr>
<td>$I_{OUT}$ Output current</td>
<td>0</td>
<td>1</td>
<td>A</td>
</tr>
<tr>
<td>$T_J$ Operating junction temperature</td>
<td>–40</td>
<td>125</td>
<td>°C</td>
</tr>
</tbody>
</table>

6.4 Thermal Information

<table>
<thead>
<tr>
<th>THERMAL METRIC(1)</th>
<th>TPS737xx-Q1</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>$R_{JA}$ Junction-to-ambient thermal resistance</td>
<td>52.2</td>
<td>°C/W</td>
</tr>
<tr>
<td>$R_{JC(top)}$ Junction-to-case (top) thermal resistance</td>
<td>59.4</td>
<td>°C/W</td>
</tr>
<tr>
<td>$R_{JB}$ Junction-to-board thermal resistance</td>
<td>19.3</td>
<td>°C/W</td>
</tr>
<tr>
<td>$\psi_{JT}$ Junction-to-top characterization parameter</td>
<td>2</td>
<td>°C/W</td>
</tr>
<tr>
<td>$\psi_{JB}$ Junction-to-board characterization parameter</td>
<td>19.3</td>
<td>°C/W</td>
</tr>
<tr>
<td>$R_{JC(bot)}$ Junction-to-case (bottom) thermal resistance</td>
<td>11.8</td>
<td>°C/W</td>
</tr>
</tbody>
</table>

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.
6.5 Electrical Characteristics

over operating temperature range (T_J = –40°C to 125°C), V_IN = (V_OUT(nom) + 1 V) (1), I_OUT = 10 mA, V_EN = 2.2 V, C_OUT = 2.2 µF (unless otherwise noted). Typical values are at T_J = 25°C.

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>V_IN</td>
<td>Input voltage range (1)(2)</td>
<td>2.2</td>
<td>5.5</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>V_FB</td>
<td>Internal reference (TPS73701)</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>V_OUT</td>
<td>Output voltage range (TPS73701)</td>
<td>V_FB</td>
<td>5.5 – V_DO</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td></td>
<td>Nominal</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>T_J = 25°C</td>
<td>–1</td>
<td>1</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>5.36 V &lt; V_IN &lt; 5.5 V, V_OUT = 5.08 V, 10 mA &lt; I_OUT &lt; 800 mA, –40°C &lt; T_J &lt; 85°C, TPS73701</td>
<td>–2</td>
<td>2</td>
<td></td>
<td>%</td>
</tr>
<tr>
<td></td>
<td>Over V_IN, I_OUT, and temperature</td>
<td>V_OUT + 0.5 V ≤ V_IN ≤ 5.5 V, 10 mA ≤ I_OUT ≤ 1 A</td>
<td>–3</td>
<td>±0.5</td>
<td>3</td>
</tr>
<tr>
<td>ΔV_OUT% / ΔV_IN</td>
<td>Line regulation (1)</td>
<td>V_OUT(nom) + 0.5 V ≤ V_IN ≤ 5.5 V</td>
<td>0.01</td>
<td>%/V</td>
<td></td>
</tr>
<tr>
<td>ΔV_OUT% / ΔI_OUT</td>
<td>Load regulation</td>
<td>1 mA ≤ I_OUT ≤ 1 A</td>
<td>0.002</td>
<td>%/mA</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>10 mA ≤ I_OUT ≤ 1 A</td>
<td>0.0005</td>
<td></td>
<td></td>
</tr>
<tr>
<td>V_DO</td>
<td>Dropout voltage (V_IN = V_OUT(nom) – 0.1 V)</td>
<td>I_OUT = 1 A</td>
<td>130</td>
<td>500</td>
<td>mV</td>
</tr>
<tr>
<td>Z_DO(DO)</td>
<td>Output impedance in dropout</td>
<td>2.2 V ≤ V_IN ≤ V_OUT + V_DO</td>
<td>0.25</td>
<td>Ω</td>
<td></td>
</tr>
<tr>
<td>I_CL</td>
<td>Output current limit</td>
<td>V_OUT = 0.9 × V_OUT(nom)</td>
<td>1.05</td>
<td>1.6</td>
<td>2.2 A</td>
</tr>
<tr>
<td>I_SC</td>
<td>Short-circuit current</td>
<td>V_OUT = 0 V</td>
<td>450</td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>I_REV</td>
<td>Reverse leakage current (–I_IN)</td>
<td>V_EN ≤ 0.5 V, 0 V ≤ V_IN ≤ V_OUT</td>
<td>0.1</td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td>I_GND</td>
<td>GND pin current</td>
<td>I_OUT = 10 mA (I_G)</td>
<td>400</td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td></td>
<td></td>
<td>I_OUT = 1 A</td>
<td>1300</td>
<td></td>
<td>µA</td>
</tr>
<tr>
<td>I_SHDN</td>
<td>Shutdown current (I_GND)</td>
<td>V_EN ≤ 0.5 V, V_OUT ≤ V_IN ≤ 5.5 V</td>
<td>20</td>
<td></td>
<td>nA</td>
</tr>
<tr>
<td>I_FB</td>
<td>FB pin current (TPS73701)</td>
<td></td>
<td>0.1</td>
<td>0.6</td>
<td>µA</td>
</tr>
<tr>
<td>PSRR</td>
<td>Power-supply rejection ratio (ripple rejection)</td>
<td>f = 100 Hz, I_OUT = 1 A</td>
<td>58</td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td></td>
<td></td>
<td>f = 10 kHz, I_OUT = 1 A</td>
<td>37</td>
<td></td>
<td></td>
</tr>
<tr>
<td>V_N</td>
<td>Output noise voltage</td>
<td>C_OUT = 10 µF</td>
<td>27 × V_OUT</td>
<td>µV RMS</td>
<td></td>
</tr>
<tr>
<td>I_STR</td>
<td>Startup time</td>
<td>V_OUT = 3 V, R_L = 30 Ω, C_OUT = 1 µF</td>
<td>600</td>
<td></td>
<td>µs</td>
</tr>
<tr>
<td>V_EN(HI)</td>
<td>EN pin high (enabled)</td>
<td>V_EN = 5.5 V</td>
<td>1.7</td>
<td>V_IN</td>
<td></td>
</tr>
<tr>
<td>V_EN(LO)</td>
<td>EN pin low (shutdown)</td>
<td>0</td>
<td>0.5</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>I_EN(HI)</td>
<td>EN pin current (enabled)</td>
<td></td>
<td>20</td>
<td></td>
<td>nA</td>
</tr>
<tr>
<td>T_SD</td>
<td>Thermal shutdown temperature</td>
<td>Shutdown, temperature increasing</td>
<td>160</td>
<td></td>
<td>°C</td>
</tr>
<tr>
<td></td>
<td>Reset, temperature decreasing</td>
<td>140</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>T_J</td>
<td>Operating junction temperature</td>
<td>–40</td>
<td>125</td>
<td></td>
<td>°C</td>
</tr>
</tbody>
</table>

(1) Minimum V_IN = V_OUT + V_DO or 2.2 V, whichever is greater.
(2) For V_OUT(nom) < 1.6 V, when V_IN ≤ 1.6 V, the output locks to V_IN and may result in an overvoltage condition on the output. To avoid this situation, disable the device before powering down V_IN.
(3) TPS73701 is tested at V_OUT = 1.2 V.
(4) Tolerance of external resistors not included in this specification.
(5) V_DO is not measured for fixed output versions with V_OUT(nom) < 2.3 V, because minimum V_IN = 2.2 V.
(6) Fixed-voltage versions only; see the Reverse Current section for more information.
6.6 Typical Characteristics

\( T_J = 25^\circ C, V_{IN} = (V_{OUT(nom)} + 1 \, V), I_{OUT} = 10 \, mA, V_{EN} = 2.2 \, V, C_{OUT} = 2.2 \, \mu F \) (unless otherwise noted)

---

**Figure 1. Load Regulation**

**Figure 2. Line Regulation**

**Figure 3. Dropout Voltage vs Output Current**

**Figure 4. Dropout Voltage vs Temperature**

**Figure 5. Output Voltage Histogram**

**Figure 6. Dropout Voltage Drift Histogram**
Typical Characteristics (continued)

\[ T_J = 25^\circ C, \quad V_{IN} = (V_{OUT(nom)} + 1\ V), \quad I_{OUT} = 10\ mA, \quad V_{EN} = 2.2\ V, \quad C_{OUT} = 2.2\ \mu F \] (unless otherwise noted)

**Figure 7. Ground Pin Current vs Output Current**

**Figure 8. Ground Pin Current vs Temperature**

**Figure 9. Ground Pin Current In Shutdown vs Temperature**

**Figure 10. Current Limit vs V_{OUT} (Foldback)**

**Figure 11. Current Limit vs V_{IN}**

**Figure 12. Current Limit vs Temperature**
Typical Characteristics (continued)

\[ T_J = 25^\circ C, \ V_{IN} = (V_{OUT(nom)} + 1 \ V), \ I_{OUT} = 10 \ mA, \ V_{EN} = 2.2 \ V, \ C_{OUT} = 2.2 \ \mu F \] (unless otherwise noted)

![Figure 13. PSRR (Ripple Rejection) vs Frequency](image)

![Figure 14. PSRR (Ripple Rejection) vs \( V_{IN} - V_{OUT} \)](image)

![Figure 15. Noise Spectral Density](image)

![Figure 16. TPS73701 RMS Noise Voltage vs \( C_{FB} \)](image)

![Figure 17. RMS Noise Voltage vs \( C_{OUT} \)](image)

![Figure 18. RMS Noise Voltage vs \( C_{NR} \)](image)
Typical Characteristics (continued)

\[ T_J = 25^\circ C, \ V_{IN} = (V_{OUT(nom)} + 1 \ V), \ I_{OUT} = 10 \ mA, \ V_{EN} = 2.2 \ V, \ C_{OUT} = 2.2 \ \mu F \] (unless otherwise noted)

**Figure 19. TPS73733 Load Transient Response**

**Figure 20. TPS73733 Line Transient Response**

**Figure 21. TPS73701 Turn-On Response**

**Figure 22. TPS73701 Turn-Off Response**

**Figure 23. TPS73701, \ V_{OUT} = 3.3 \ V**

Power-Up And Power-Down

**Figure 24. I_{ENABLE} vs Temperature**
Typical Characteristics (continued)

\[ T_J = 25°C, \ V_{IN} = (V_{OUT(nom)} + 1 \text{ V}), I_{OUT} = 10 \text{ mA}, \ V_{EN} = 2.2 \text{ V}, \ C_{OUT} = 2.2 \mu\text{F} \] (unless otherwise noted)

![Figure 25. TPS73701 I_FFB vs Temperature](image1)

![Figure 26. TPS73701 I_FFB vs Temperature](image2)

![Figure 27. TPS73701 Load Transient, Adjustable Version](image3)

![Figure 28. TPS73701 Line Transient, Adjustable Version](image4)
Detailed Description

7.1 Overview
The TPS737xx-Q1 belongs to a family of new generation LDO regulators that use an NMOS pass transistor to achieve ultra-low-dropout performance, reverse current blockage, and freedom from output capacitor constraints. These features combined with an enable input make the TPS737xx-Q1 ideal for portable applications. This regulator family offers a wide selection of fixed output voltage versions and an adjustable output version. All versions have thermal and over-current protection, including foldback current limit.

Table 1. Standard 1% Resistor Values for Common Output Voltages

<table>
<thead>
<tr>
<th>V_{OUT}</th>
<th>R_1</th>
<th>R_2</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.2 V</td>
<td>Short</td>
<td>Open</td>
</tr>
<tr>
<td>1.5 V</td>
<td>23.2 kΩ</td>
<td>95.3 kΩ</td>
</tr>
<tr>
<td>1.8 V</td>
<td>28 kΩ</td>
<td>56.2 kΩ</td>
</tr>
<tr>
<td>2.5 V</td>
<td>39.2 kΩ</td>
<td>36.5 kΩ</td>
</tr>
<tr>
<td>2.8 V</td>
<td>44.2 kΩ</td>
<td>33.2 kΩ</td>
</tr>
<tr>
<td>3 V</td>
<td>46.4 kΩ</td>
<td>33.2 kΩ</td>
</tr>
<tr>
<td>3.3 V</td>
<td>52.3 kΩ</td>
<td>30.1 kΩ</td>
</tr>
</tbody>
</table>

7.2 Functional Block Diagrams

![Figure 29. Fixed Voltage Version](image-url)
7.3 Feature Description

7.3.1 Output Noise

A precision bandgap reference is used to generate the internal reference voltage ($V_{\text{REF}}$). This reference is the dominant noise source within the TPS737xx-Q1 and it generates approximately $32 \ \mu V_{\text{RMS}}$ (10 Hz to 100 kHz) at the reference output (NR). The regulator control loop adds gain to the reference noise with the same gain as the reference voltage, so that the noise voltage of the regulator is approximately given by Equation 1.

$$V_N = 32 \ \mu V_{\text{RMS}} \times \frac{(R_1 + R_2)}{R_2} = 32 \ \mu V_{\text{RMS}} \times \frac{V_{\text{OUT}}}{V_{\text{REF}}}$$

(1)

Because the value of $V_{\text{REF}}$ is 1.2 V, this relationship reduces to:

$$V_N (\mu V_{\text{RMS}}) = 27 \left( \frac{\mu V_{\text{RMS}}}{V} \right) \times V_{\text{OUT}} (V)$$

(2)

for the case of no $C_{\text{NR}}$.

An internal 27-kΩ resistor in series with the noise reduction pin (NR) forms a low-pass filter for the voltage reference when an external noise reduction capacitor ($C_{\text{NR}}$) is connected from NR to ground. The total noise in the 10-Hz to 100-kHz bandwidth is reduced by a factor of approximately 3.2 for $C_{\text{NR}} = 10 \ \text{nF}$, giving the approximate relationship for $C_{\text{NR}} = 10 \ \text{nF}$ in Equation 3.

$$V_N (\mu V_{\text{RMS}}) = 8.5 \left( \frac{\mu V_{\text{RMS}}}{V} \right) \times V_{\text{OUT}} (V)$$

(3)

This noise reduction effect is shown in Figure 18.

The TPS737xx-Q1 uses an internal charge pump to develop an internal supply voltage sufficient to drive the gate of the NMOS pass element above $V_{\text{OUT}}$. The charge pump generates approximately 250 µV of switching noise at approximately 4 MHz, however, charge-pump noise contribution is negligible at the output of the regulator for most values of $I_{\text{OUT}}$ and $C_{\text{OUT}}$. 

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**Figure 30. Adjustable Voltage Version**

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See Table 1 for standard resistor values.
Feature Description (continued)

7.3.2 Internal Current Limit

The TPS737xx-Q1 internal current limit helps protect the regulator during fault conditions. Foldback current limit helps to protect the regulator from damage during output short-circuit conditions by reducing current limit when $V_{\text{OUT}}$ drops below 0.5 V. See Figure 10.

7.3.3 Enable Pin and Shutdown

The enable pin (EN) is active high and is compatible with standard TTL-CMOS levels. A $V_{\text{EN}}$ below 0.5 V (maximum) turns the regulator off and drops the GND pin current to approximately 10 nA. When EN is used to shutdown the regulator, all charge is removed from the pass transistor gate, and the output ramps back up to a regulated $V_{\text{OUT}}$ (see Figure 21).

When shutdown capability is not required, EN can be connected to $V_{\text{IN}}$. However, the pass gate may not be discharged using this configuration, and the pass transistor may be left on (enhanced) for a significant time after $V_{\text{IN}}$ is removed. This scenario can result in reverse current flow (if the IN pin is low impedance) and faster ramp times upon power-up. In addition, for $V_{\text{IN}}$ ramp times slower than a few milliseconds, the output may overshoot upon power-up.

7.3.4 Reverse Current

The NMOS pass element of the TPS737xx-Q1 provides inherent protection against current flow from the output of the regulator to the input when the gate of the pass device is pulled low. To ensure that all charge is removed from the gate of the pass element, the EN pin must be driven low before the input voltage is removed. If this is not done, the pass element may be left on because of stored charge on the gate.

After the EN pin is driven low, no bias voltage is required on any pin for reverse current blocking. Reverse current is specified as the current flowing out of the IN pin because of voltage applied on the OUT pin. There is additional current flowing into the OUT pin as a result of the 80-kΩ internal resistor divider to ground (see Figure 29 and Figure 30).

For the TPS73701, reverse current may flow when $V_{\text{FB}}$ is more than 1 V above $V_{\text{IN}}$.

7.3.5 Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately 160°C, allowing the device to cool. When the junction temperature cools to approximately 140°C, the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the dissipation of the regulator, protecting it from damage due to overheating.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. Junction temperature must be limited to 125°C maximum for reliable operation. To estimate the margin of safety in a complete design (including heatsink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions. Thermal protection must trigger at least 35°C above the maximum expected ambient condition of your application for good reliability. This produces a worst-case junction temperature of 125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS737xx-Q1 is designed to protect against overload conditions. It was not intended to replace proper heatsinking. Continuously running the TPS737xx-Q1 into thermal shutdown degrades device reliability.

7.4 Device Functional Modes

Driving the EN pin over 1.7 V turns on the regulator. Driving the EN below 0.5 V causes the regulator to enter shutdown mode. In shutdown, the current consumption of the device is reduced to 20 nA (typical).
8 Application and Implementation

NOTE
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI’s customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information
The TPS737xx-Q1 family of LDO regulators use an NMOS pass transistor to achieve ultra-low-dropout performance, reverse current blockage, and freedom from output capacitor constraints. These features, combined with low noise and an enable input, make the TPS737xx-Q1 ideal for portable applications.

8.2 Typical Application

![TYPICAL APPLICATION CIRCUIT FOR FIXED-VOLTAGE VERSION](image1)

![TYPICAL APPLICATION CIRCUIT FOR ADJUSTABLE-VOLTAGE VERSION](image2)

8.2.1 Design Requirements
R₁ and R₂ can be calculated for any output voltage using the formula shown in Figure 32. Sample resistor values for common output voltages are shown in Table 1.

Make the parallel combination of R₁ and R₂ approximately equal to 19 kΩ for best accuracy. This 19 kΩ, in addition to the internal 8-kΩ resistor, presents the same impedance to the error amplifier as the 27-kΩ bandgap reference output. This impedance helps compensate for leakages into the error amplifier terminals.

The TPS73701 adjustable version does not have the NR pin available. However, connecting a feedback capacitor (C_FB) from the output to the feedback pin (FB) reduces output noise and improves load transient performance. This capacitor must be limited to 0.1 µF.
Typical Application (continued)

8.2.2 Detailed Design Procedure

8.2.2.1 Input and Output Capacitor Requirements

Although an input capacitor is not required for stability, if input impedance is very low, it is good analog design practice to connect a 0.1-µF to 1-µF low equivalent series resistance (ESR) capacitor across the input supply near the regulator. This capacitor counteracts reactive input sources and improves transient response, noise rejection, and ripple rejection. A higher-value capacitor may be necessary if large, fast rise-time load transients are anticipated or the device is located several inches from the power source.

The TPS737xx-Q1 requires a 1-µF output capacitor for stability. It is designed to be stable for all available types and values of capacitors. In applications where multiple low ESR capacitors are in parallel, ringing may occur when the product of $C_{\text{OUT}}$ and total ESR drops below 50 nΩF. Total ESR includes all parasitic resistances, including capacitor ESR and board, socket, and solder joint resistance. In most applications, the sum of capacitor ESR and trace resistance meets this requirement.

8.2.2.2 Dropout Voltage

The TPS737xx-Q1 uses an NMOS pass transistor to achieve extremely low dropout. When $(V_{\text{IN}} - V_{\text{OUT}})$ is less than the dropout voltage ($V_{\text{DO}}$), the NMOS pass device is in its linear region of operation and the input-to-output resistance is the $R_{\text{DS(ON)}}$ of the NMOS pass element.

The TPS737xx-Q1 requires a larger voltage drop from $V_{\text{IN}}$ to $V_{\text{OUT}}$ to avoid degraded transient response for large step changes in load current. The boundary of this transient dropout region is approximately twice the DC dropout. Values of $V_{\text{IN}} - V_{\text{OUT}}$ above this line ensure normal transient response.

Operating in the transient dropout region can cause an increase in recovery time. The time required to recover from a load transient is a function of the magnitude of the change in load current rate, the rate of change in load current, and the available headroom ($V_{\text{IN}}$ to $V_{\text{OUT}}$ voltage drop). Under worst-case conditions (full-scale instantaneous load change with $(V_{\text{IN}} - V_{\text{OUT}})$ close to DC dropout levels), the TPS737xx-Q1 can take a couple of hundred microseconds to return to the specified regulation accuracy.

8.2.2.3 Transient Response

The low open-loop output impedance provided by the NMOS pass element in a voltage follower configuration allows operation without a 1-µF output capacitor. As with any regulator, the addition of additional capacitance from the OUT pin to ground reduces undershoot magnitude but increases its duration. In the adjustable version, the addition of a capacitor ($C_{\text{FB}}$) between the OUT pin and the FB pin also improves the transient response.

The TPS737xx-Q1 does not have active pulldown when the output is overvoltage. This architecture allows for applications that connect higher voltage sources, such as alternate power supplies, to be connected to the output. This architecture also results in an output overshoot of several percent if the load current quickly drops to zero when a capacitor is connected to the output. The duration of overshoot can be reduced by adding a load resistor. The overshoot decays at a rate determined by the output capacitor ($C_{\text{OUT}}$) and the internal and external load resistance. The rate of decay is given by Equation 4 and Equation 5.

(Fixed voltage version)
\[
\frac{dV}{dT} = \frac{V_{\text{OUT}}}{C_{\text{OUT}} \times 80 \, \text{kΩ} \parallel R_{\text{LOAD}}} \tag{4}
\]

(Adjustable voltage version)
\[
\frac{dV}{dT} = \frac{V_{\text{OUT}}}{C_{\text{OUT}} \times 80 \, \text{kΩ} \parallel (R_1 + R_2) \parallel R_{\text{LOAD}}} \tag{5}
\]
Typical Application (continued)

8.2.3 Application Curves

9  Power Supply Recommendations

The device is designed to operate from an input voltage supply range from 2.2 V to 5.5 V. The input voltage range provides adequate headroom for the device to have a regulated output. This input supply must be well regulated. If the input supply is noisy, additional input capacitors with low ESR help improve the output noise performance.

10  Layout

10.1  Layout Guidelines

10.1.1  Improve PSRR and Noise Performance

TI recommends that the printed circuit board (PCB) be designed with separate ground planes for $V_{IN}$ and $V_{OUT}$, with each ground plane connected only at the GND pin of the device, to improve AC performance such as PSRR, output noise, and transient response. In addition, the ground connection for the bypass capacitor must connect directly to the GND pin of the device.

10.1.2  Power Dissipation

The ability to remove heat from the die is different for each package type, presenting different considerations in the PCB layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Performance data for JEDEC low-K and high-K boards are shown in Thermal Information. Using heavier copper increases the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers also improves the heatsink effectiveness.

Power dissipation depends on input voltage and load conditions. Power dissipation ($P_D$) is equal to the product of the output current multiplied by the voltage drop across the output pass element ($V_{IN}$ to $V_{OUT}$). See Equation 6.

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT}$$  \hspace{1cm} (6)

Power dissipation can be minimized by using the lowest possible input voltage necessary to assure the required output voltage.
10.2 Layout Example

Figure 35. Layout Diagram
11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation see the following:
*Solder Pad Recommendations for Surface-Mount Devices* (SBFA015)

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Community Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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11.4 Trademarks

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11.5 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 Glossary

SLYZ022 — *TI Glossary.*

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

12.1 Package Mounting

See *Solder Pad Recommendations for Surface-Mount Devices* (SBFA015) for TPS737xx-Q1 solder pad footprint recommendations.
# PACKAGE OPTION ADDENDUM

## PACKAGING INFORMATION

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<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan (2)</th>
<th>Lead finish/ Ball material (6)</th>
<th>MSL Peak Temp (3)</th>
<th>Op Temp (°C)</th>
<th>Device Marking (4/5)</th>
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(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) **MSL, Peak Temp.** - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF TPS737-Q1:

- Catalog: TPS737

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
### TAPE AND REEL INFORMATION

#### TAPE DIMENSIONS

- **A0**: Dimension designed to accommodate the component width
- **B0**: Dimension designed to accommodate the component length
- **K0**: Dimension designed to accommodate the component thickness
- **W**: Overall width of the carrier tape
- **P1**: Pitch between successive cavity centers

**Pocket Quadrants**

- **Q1**
- **Q2**
- **Q3**
- **Q4**

**Sprocket Holes**

**User Direction of Feed**

*All dimensions are nominal*

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*All dimensions are nominal*
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.
NOTES:
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.
NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
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